CSHD6-60C

SURFACE MOUNT SILICON DUAL, COMMON CATHODE SCHOTTKY RECTIFIER 6.0 AMP, 60 VOLT



Semiconductor Corp.

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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CSHD6-60C is a silicon Schottky rectifier designed for fast switching applications requiring a low forward voltage drop.

MARKING: FULL PART NUMBER

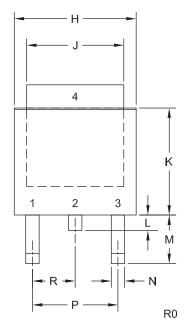
TINGS: (T _C =25°C unless otherwise					
	SYMBOL		UNITS		
e Reverse Voltage	V _{RRM}	60	V		
ed Forward Current (T _C =120°C)	IO	6.0	А		
Surge Current, tp=10ms	IFSM	50	А		
e Reverse Surge Current, tp=2.0µs	IRRM	1.0	А		
Critical Rate of Rise of Reverse Voltage		10,000	V/µs		
Storage Junction Temperature	TJ, T _{stg}	-65 to +150	°C		
ance Per Diode	Θ^{JC}	3.5	°C/W		
ELECTRICAL CHARACTERISTICS PER DIODE: (T _C =25°C unless otherwise noted)					
TEST CONDITIONS	TYP	MAX	UNITS		
√ _R =60∨	7.0	30	μA		
V _R =60V, T _C =125°C	7.0	10	mA		
F=3.0A	0.61	0.70	V		
F=3.0A, T _C =125°C	0.55	0.65	V		
F=6.0A	0.80	0.90	V		
_F =6.0A, T _C =125°C	0.66	0.85	V		
	e Reverse Voltage ed Forward Current (T_C =120°C) Surge Current, tp=10ms e Reverse Surge Current, tp=2.0µs Rise of Reverse Voltage Storage Junction Temperature ance Per Diode CHARACTERISTICS PER DIODE: WR=60V VR=60V VR=60V, T _C =125°C IF=3.0A IF=3.0A, T _C =125°C	SYMBOLa Reverse Voltage V_{RRM} ed Forward Current (T_C =120°C) I_O Surge Current, tp=10ms I_{FSM} b Reverse Surge Current, tp=2.0µs I_{RRM} Rise of Reverse Voltage dv/dt Storage Junction Temperature T_J , T_{stg} ance Per Diode Θ_{JC} CHARACTERISTICS PER DIODE: $(T_C=25°C \text{ unless})$ TEST CONDITIONSTYP $V_R=60V$ 7.0 $V_R=60V$, $T_C=125°C$ 7.0 $V_R=60V$, $T_C=125°C$ 0.55 $I_F=3.0A$ 0.61 $I_F=3.0A$, $T_C=125°C$ 0.80	SYMBOL e Reverse Voltage V_{RRM} 60 ed Forward Current (T_C =120°C) I _O 6.0 Surge Current, tp=10ms IFSM 50 e Reverse Surge Current, tp=2.0µs I _{RRM} 1.0 Rise of Reverse Voltage dv/dt 10,000 Storage Junction Temperature TJ, T _{stg} -65 to +150 ance Per Diode Θ_{JC} 3.5 CHARACTERISTICS PER DIODE: (T_C =25°C unless otherwise noted) MAX VR=60V 7.0 30 VR=60V, T_C=125°C 7.0 10 I=3.0A 0.61 0.70 I=5.0A, T_C=125°C 0.65 0.65 I=6.0A 0.80 0.90		

R10 (1-March 2016)





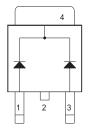
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LEAD CODE:

- 1) Anode 1
- 2) Cathode
- 3) Anode 2
- 4) Cathode
- Pin 2 is common to the tab (4)

MARKING: FULL PART NUMBER



DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
А	0.083	0.108	2.10	2 <u>.</u> 75		
В	0.016	0.032	0.40	0.81		
С	0.035	0.063	0.89	1.60		
D	0.203	0.228	5.15	5.79		
E	0.020	-	0.51	-		
F	0.018	0.024	0.45	0.60		
G	0.051	0.071	1.30	1.80		
Н	0.248	0.268	6.30	6.81		
J	0.197	0.217	5.00	5.50		
K	0.209	0.245	5.30	6.22		
L	0.025	0.040	0.64	1.02		
М	0.090	0.115	2.30	2 <u>.</u> 91		
N	0.012	0.045	0.30	1.14		
Р	0.180		4.60			
R	0.090		2.30			
DPAK (REV: R0)						

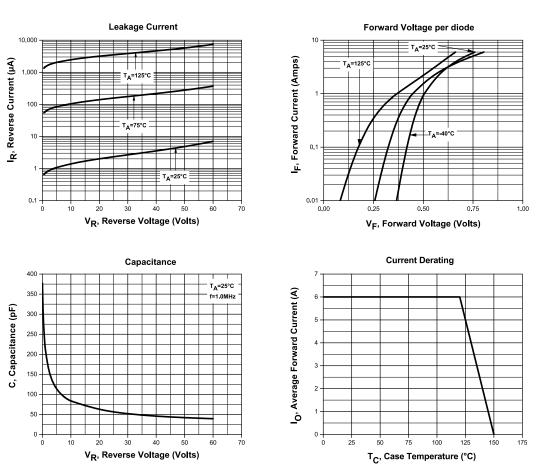
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DPAK CASE - MECHANICAL OUTLINE



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TYPICAL ELECTRICAL CHARACTERISTICS

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- Inventory bonding
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- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
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- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits

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Custom product and package development

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- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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